IN THE CLAIMS:

1. (Previously Presented) A light emitting element, comprising a light emitting element layer between a first electrode and a second electrode, wherein

one of the first electrode and the second electrode is disposed as a light-emitting-side electrode on a side from which light is emitted to outside,

another one of the first electrode and the second electrode, which is formed as a back-side electrode positioned on a back side of the light-emitting-side electrode, is formed as a semitransparent electrode for partially transmitting incident light from a side of the light emitting element layer,

an antireflective layer is provided on a back side of the semitransparent electrode, and

a metal layer with a mesh pattern provided with apertures for transmitting light is used in the semitransparent electrode.

2-3. (Canceled)

4. (Previously Presented) A light emitting element according to claim 1, wherein a chromium oxide is used in the antireflective layer.

5. (Currently Amended) A light emitting display which includes a plurality of pixels arranged in a matrix along a row direction and a column direction in a display section, comprising a light emitting element with a light emitting element layer provided between a first electrode and a second electrode in each of the plurality of pixels, ~~pixel,~~ wherein

the first electrode is provided for each pixel and has an individual shape, and is formed over a transparent substrate disposed on a side from which light is emitted to outside of the display and is an electrode capable of transmitting light emitted from the light emitting element layer,

the second electrode is formed as a common electrode for the plurality of pixels arranged in the matrix along the row direction and the column direction in the display section,

and is formed on a back side of the first electrode so as to be opposed to the first electrode with the light emitting element layer interposed therebetween and is a semitransparent electrode for partially transmitting incident light from a side of the light emitting element layer, and

an antireflective layer is provided on the second electrode on a back side of the second electrode, as a common layer for the plurality of pixels arranged in the matrix along the row direction and the column direction in the display section.

6. (Previously Presented) A light emitting display according to claim 5, wherein a metal layer with a mesh pattern provided with apertures for transmitting light is used in the semitransparent electrode.

7. (Original) A light emitting display according to claim 5, wherein an Ag layer or an MgAg layer with a thickness of 20 nm or less is used in the semitransparent electrode.

8. (Previously Presented) A light emitting display according to claim 5, wherein a chromium oxide is used in the antireflective layer.

9. (Previously Presented) A light emitting display according to claim 5, each pixel comprising, in addition to the light emitting element, a thin-film transistor for controlling light emission from the light emitting element, wherein

the thin-film transistor is formed closer to the substrate than the light emitting element, and

an antireflective light-blocking layer for blocking entry of ambient light and for preventing reflection of ambient light is provided between at least a region where an active layer of the thin-film transistor is formed and the substrate.

10. (Currently Amended) A display which includes a plurality of pixels arranged in a matrix along a row direction and a column direction in a display section, comprising an electroluminescence element with a light emitting element layer provided between an anode and a cathode in each of the plurality of pixels. ~~pixel.~~ wherein

the anode is provided for each pixel and has an individual shape, and is formed over a transparent substrate disposed on a side from which light is emitted to outside and comprises an electrode capable of transmitting light emitted from the light emitting element layer,

the cathode is formed as a common electrode for all the plurality of pixels arranged in the matrix along the row direction and the column direction in the display section, and is formed on a back side of the anode so as to be opposed to the anode with the light emitting element layer interposed therebetween and comprises a semitransparent electrode capable of partially transmitting incident light from a side of the light emitting element layer, and

an antireflective layer is provided on the cathode on a back side of the cathode, as a common layer for all the plurality of pixels arranged in the matrix along the row direction and the column direction in the display section.

11. (Previously Presented) A display according to claim 10, wherein a metal layer with a mesh pattern provided with apertures for transmitting light is used in the semitransparent electrode.

12. (Original) A display according to claim 10, wherein an Ag layer or an MgAg layer with a thickness of 20 nm or less is used in the semitransparent electrode.

13. (Previously Presented) A display according to claim 10, wherein a chromium oxide is used in the antireflective layer.

14. (Previously Presented) A display according to claim 10, each pixel comprising, in addition to the electroluminescence element, a thin-film transistor for controlling light emission from the electroluminescence element, wherein

the thin-film transistor is formed closer to the substrate than the electroluminescence element, and

an antireflective light-blocking layer for blocking entry of ambient light and for preventing reflection of ambient light is provided between at least a region where an active layer of the thin-film transistor is formed and the substrate.

15. (Previously Presented) A light emitting element according to claim 1, wherein the metal layer with the mesh pattern is formed using aluminum.

16. (Previously Presented) A light emitting display, comprising a light emitting element with a light emitting element layer provided between a first electrode and a second electrode, wherein

the first electrode is formed over a transparent substrate disposed on a side from which light is emitted to outside of the display and is an electrode capable of transmitting light emitted from the light emitting element layer,

the second electrode is formed on a back side of the first electrode so as to be opposed to the first electrode with the light emitting element layer interposed therebetween and is a semitransparent electrode for partially transmitting incident light from a side of the light emitting element layer,

an antireflective layer is provided on a back side of the second electrode, and

a metal layer with a mesh pattern provided with apertures for transmitting light is used in the semitransparent electrode.

17. (Previously Presented) A display, comprising an electroluminescence element with a light emitting element layer provided between an anode and a cathode, wherein

the anode is formed over a transparent substrate disposed on a side from which light is emitted to outside and comprises an electrode capable of transmitting light emitted from the light emitting element layer,

the cathode is formed on a back side of the anode so as to be opposed to the anode with the light emitting element layer interposed therebetween and comprises a semitransparent electrode capable of partially transmitting incident light from a side of the light emitting element layer,

an antireflective layer is formed on a back side of the cathode, and

a metal layer with a mesh pattern provided with apertures for transmitting light is used in the semitransparent electrode.

18. (Currently Amended) A light emitting display according to claim 5, wherein a metal layer with a thickness reduced to a level of a thin film through which light can be partially transmitted is used as the semitransparent electrode.

19. (Currently Amended) A display according to claim 10, wherein a metal layer with a thickness reduced to a level of a thin film through which light can be partially transmitted is used as the semitransparent electrode.

20. (Previously Presented) A light emitting display according to claim 5, wherein molybdenum is used in the antireflective layer.

21. (Previously Presented) A display according to claim 10, wherein molybdenum is used in the antireflective layer.